



DONGGUAN NANJING ELECTRONICS LTD.,  
**TO-247-3 Silicon Carbide Schottky Diode**

**NJ12040U3** SiC Diode 1200V, 40A, 107nC

### General Description

This product family offers state of the art performance. It is designed for high frequency applications here high efficiency and high reliability are required.

### Features

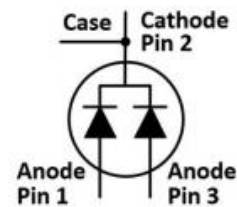
- Max junction temperature 175°C
- High surge current capacity
- Zero reverse recovery current
- Zero forward recovery voltage
- High frequency operation
- Temperature independent switching behavior
- Positive temperature coefficient on  $V_F$



**TO-247-3  
Pin definition**

### Applications

- Solar booster
- Inverter free wheeling diode
- Vienna 3-Phase PFC
- EV charger piles
- Switch Mode Power Supplies



### Key performance parameters

Type	$V_{RRM}$	$I_F$ $T_C=151^\circ\text{C}$	$Q_C$
NJ12040U3	1200V	40A	107nC

Caution: This device is sensitive to electrostatic discharge .Users should follow ESD handing procedures.

## Typical Characteristics

---

### Maximum Ratings

$T_C=25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	1200	V
DC Peak Reverse Voltage	$V_{DC}$	1200	V

### Maximum Ratings

$T_C=25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Continuous Forward Current: $T_C = 25^{\circ}\text{C}$ $T_C = 151^{\circ}\text{C}$	$I_F$	54* 20*	A
Non-Repetitive Forward Surge Current: Sine half wave $T_C = 25^{\circ}\text{C}$ $t_p = 10\text{ms}$	$I_{FSM}$	140*	A
Power Dissipation: $T_C = 25^{\circ}\text{C}$ $T_C = 150^{\circ}\text{C}$	$P_{tot}$	272* 45*	W
$i^2t$ value : $T_C = 25^{\circ}\text{C}$ $t_p = 10\text{ms}$	$\int i^2 dt$	98*	$\text{A}^2\text{S}$
Operating Junction temperature Range	$T_j$	-55 to +175	$^{\circ}\text{C}$
Storage temperature Range	$T_{stg}$	-55 to +175	$^{\circ}\text{C}$

\*Per Leg

## Typical Characteristics

### Thermal Resistance

Parameter	Symbol	Typ.	Unit
Thermal resistance of crust	$R_{thJC}$	0.55*	°C/W

\*Per Leg

### Electrical Characteristic

$T_C = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Value			Unit	Test Condition
		Min.	Typ.	Max.		
Forward Voltage	$V_F$		1.56* 2.25*	1.8* 3.0*	V	$I_F = 20\text{A}$ $T_j = 25^\circ\text{C}$ $T_j = 175^\circ\text{C}$
Reverse Current	$I_R$		10* 45*	120* 450*	$\mu\text{A}$	$V_R = 1200\text{V}$ $T_j = 25^\circ\text{C}$ $T_j = 175^\circ\text{C}$
Total Capacitive Charge	$Q_C$		107*		nC	$V_R = 800\text{V}$ $T_j = 25^\circ\text{C}$ $Q_C = \int_0^{V_R} C(V)dV$
Total Capacitance	C		1114* 100* 77*		pF	$T_j = 25^\circ\text{C}$ , $f = 1\text{MHz}$ $V_R = 1\text{V}$ $V_R = 400\text{V}$ $V_R = 800\text{V}$

\*Per Leg

Characteristics Curves

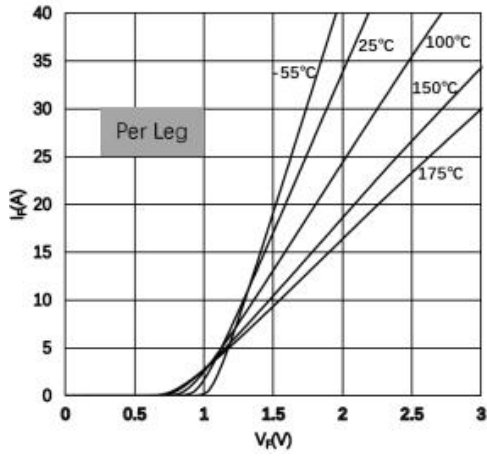


Fig. 1 Typical forward characteristic curve

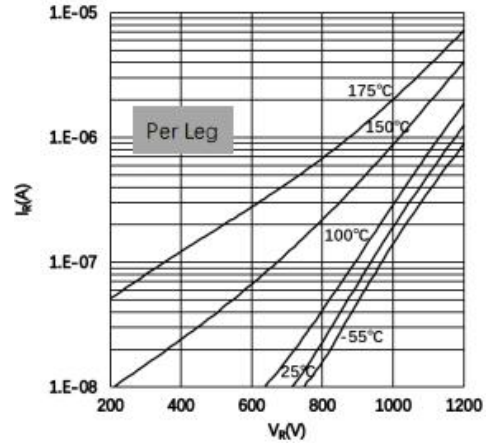


Fig. 2 Typical reverse characteristic curve

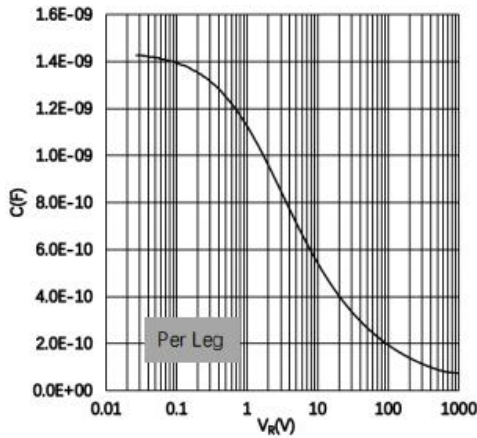


Fig. 3 Typical capacitance and reverse voltage curve

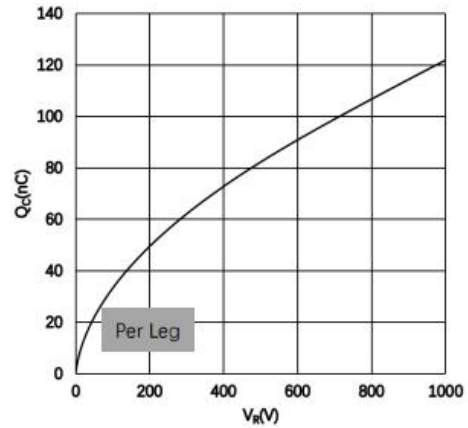


Fig. 4 Typical storage charge and reverse voltage curve

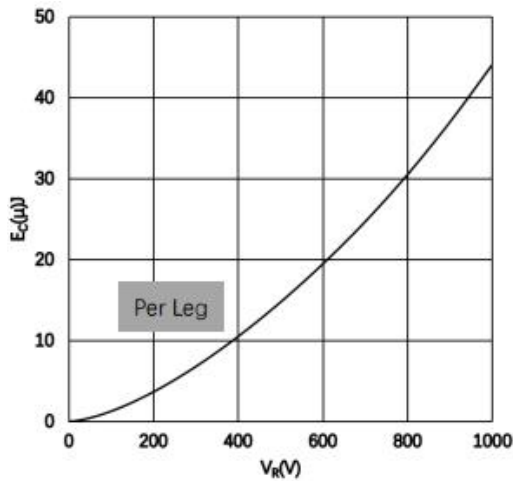


Fig. 5 Typical capacitance energy and reverse voltage curve

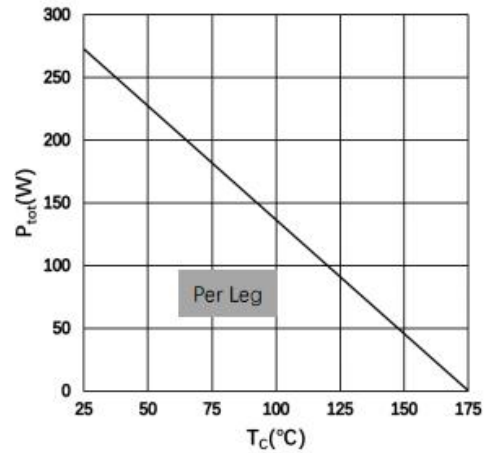


Fig. 6 Typical power derating curve

# Typical Characteristics

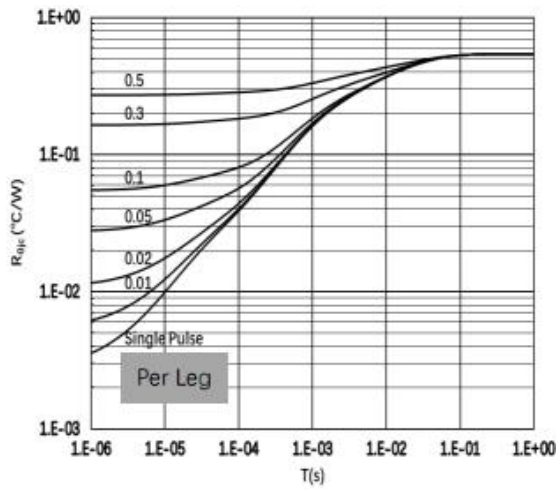


Fig. 7 Transient thermal impedance

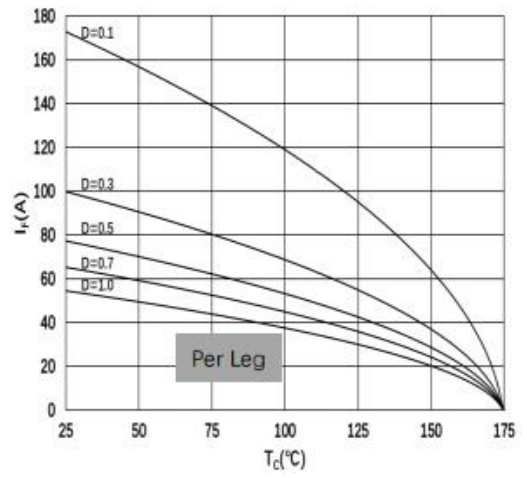


Fig. 8 Current curves under different loads

